

#### **400V PNP HIGH VOLTAGE TRANSISTOR IN SOT23**

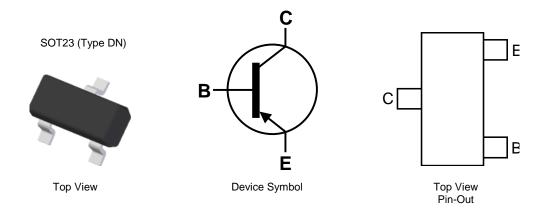
#### **Features**

- BV<sub>CEO</sub> > -400V
- I<sub>C</sub> = -150mA high Continuous Collector Current
- I<sub>CM</sub> = -500mA Peak Pulse Current
- 500mW Power Dissipation
- Excellent h<sub>FE</sub> Characteristics Up To -100mA
- Complementary NPN Type: FMMT458Q
- Totally Lead-Free & Fully RoHS compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The FMMT558Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Package: SOT23 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: 0.008 grams (Approximate)



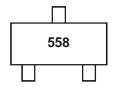
### Ordering Information (Note 4)

Orderal	ole	Packago	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
Part Number	Package	war King	Neel Size (Illulies)	rape widin (min)	Qty.	Carrier	
FMMT558	QTA	SOT23 (Type DN)	558	7	8	3000	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



558 = Product type Marking Code



### **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-400	V
Collector-Emitter Voltage	$V_{CEO}$	-400	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	Ic	-150	mA
Peak Pulse Current	I <sub>CM</sub>	-500	mA
Base Current	Ι <sub>Β</sub>	-200	mA

# Thermal Characteristics (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ hetaJA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)	$R_{ hetaJL}$	197	°C/W
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +150	°C

### ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

- 5. For a device surface mounted on 15mm X 15mm X 1.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions
- 6. Thermal resistance from junction to solder-point (at the end of the collector lead).
  7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



### **Thermal Characteristics and Derating information**

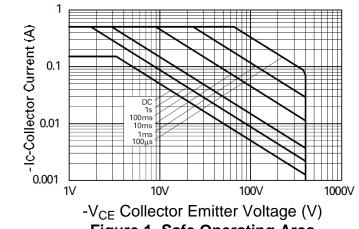


Figure 1. Safe Operating Area

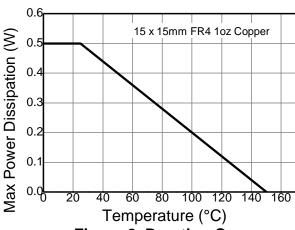
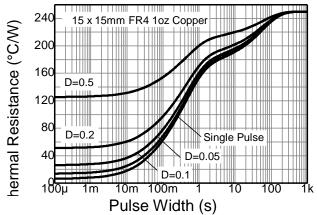


Figure 2. Derating Curve



**Figure 3. Transient Thermal Impedance** 

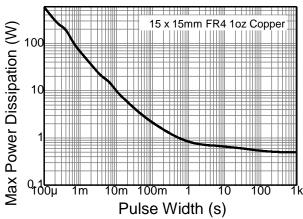


Figure 4. Pulse Power Dissipation



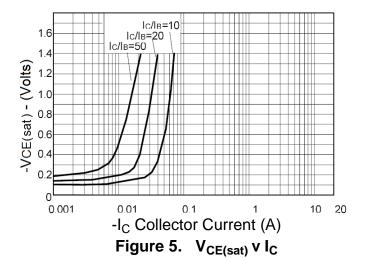
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

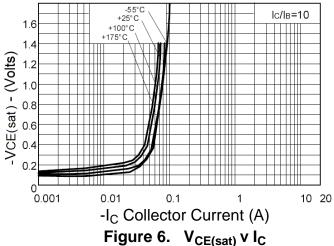
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-400	-	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-400	-	-	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-	-	V	$I_E = -100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	-	-	-100	nA	V <sub>CB</sub> = -320V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	-100	nA	V <sub>EB</sub> = -5.6V
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	-100	nA	V <sub>CE</sub> = -320V
Static Forward Current Transfer Ratio (Note 8)	h <sub>FE</sub>	100 100 15		300 -	-	$I_{C}$ = -1mA, $V_{CE}$ = -10V $I_{C}$ = -50mA, $V_{CE}$ = -10V $I_{C}$ = -100mA, $V_{CE}$ = -10V
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(sat)</sub>	-	-	-200 -500	mV mV	$I_C = -20mA$ , $I_B = -2mA$ $I_C = -50mA$ , $I_B = -6mA$
Base-Emitter Turn-On Voltage (Note 8)	V <sub>BE(on)</sub>	-	-	-0.9	V	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V
Base-Emitter Saturation Voltage (Note 8)	V <sub>BE(sat)</sub>	-	-	-0.9	V	$I_C = -50 \text{mA}, I_B = -5 \text{mA}$
Output Capacitance	C <sub>obo</sub>	-	-	5	pF	V <sub>CB</sub> = -20V, f = 1MHz
Transition Frequency	f <sub>T</sub>	50	-	-	MHz	V <sub>CE</sub> = -20V, I <sub>C</sub> = -10mA, f = 20MHz
Turn-On Time	ton	-	95	-	ns	V <sub>CE</sub> = -100V, I <sub>C</sub> = -50mA
Turn-Off Time	t <sub>off</sub>	-	1600	-	ns	$I_{B1} = 5mA$ , $I_{B2} = -10mA$

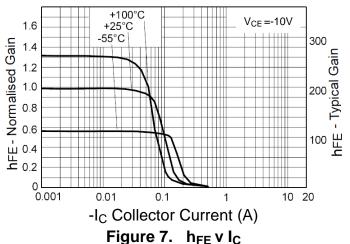
Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%

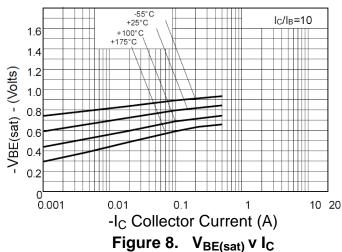


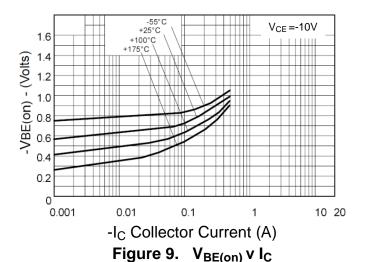
### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









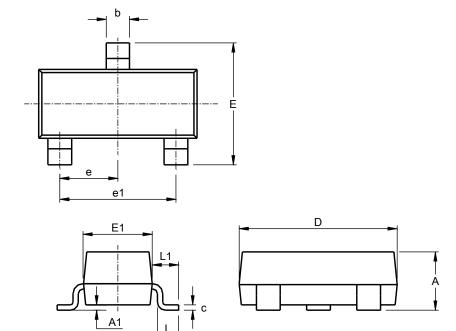




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Type DN)

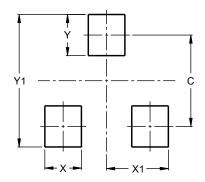


SOT23 Type DN						
Dim	Min	Max	Тур			
Α	0.89	1.12	1.00			
A1	0.01	0.10	0.05			
b	0.30	0.51	0.45			
С	0.08 0.20 0.10					
D	2.80	3.04	3.00			
Е	2.10	2.64	2.42			
E1	1.20	1.40	1.37			
е	e 0.95 REF					
e1	1.90 REF					
L	0.25	0.60	0.30			
L1	0.45	0.62	0.54			
All Dimensions in mm						

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Type DN)



Dimensions	Value (in mm)		
С	2.0		
Х	0.8		
X1	1.35		
Y	0.9		
Y1	2.9		

April 2023



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